## -30V Pch+Pch Middle Power MOSFET

V <sub>DSS</sub>	-30V
R <sub>DS(on)</sub> (Max.)	70mΩ
I <sub>D</sub>	±4.0A
$P_D$	2.0W

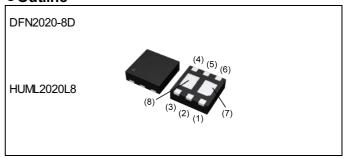
#### Features

- 1) Low on resistance.
- 2) Small Surface Mount Package.
- 3) Pb-free lead plating; RoHS compliant.
- 4) Halogen Free.

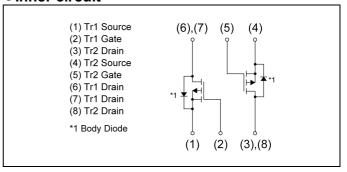
# Application

Switching

## Outline



### •Inner circuit



Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	180
Туре	Tape width (mm)	8
	Quantity (pcs)	3000
	Taping code	TCR
	Marking	JA2

# ● **Absolute maximum ratings** (T<sub>a</sub> = 25°C ,unless otherwise specified) < Tr1 and Tr2>

Parameter	Symbol	Value	Unit
Drain - Source voltage	V <sub>DSS</sub>	-30	V
Continuous drain current	I <sub>D</sub>	±4.0	А
Pulsed drain current	I <sub>DP</sub> *1	±12	А
Gate - Source voltage	V <sub>GSS</sub>	±20	V
Avalanche current, single pulse	I <sub>AS</sub> *2	-3.0	Α
Avalanche energy, single pulse	E <sub>AS</sub> *2	6.5	mJ
Power dissipation	P <sub>D</sub> *3	2.0	W
Junction temperature	T <sub>j</sub>	150	°C
Operating junction and storage temperature range	T <sub>stg</sub>	-55 to +150	°C

## ●Thermal resistance

Parameter	Cymbal	Values			Lloit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - ambient	R <sub>thJA</sub> *3	1	-	62.5	°C/W

# ● Electrical characteristics (T<sub>a</sub> = 25°C) < Tr1 and Tr2>

Damanadan	0	0 - 1141 - 11 -	Values			1.1:4	
Parameter	Parameter Symbol Conditions		Min.	Тур.	Max.	Unit	
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V$ , $I_D = -1mA$	-30	-	-	V	
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{i}}$	I <sub>D</sub> = -1mA	-	-22	-	mV/°C	
Zero gate voltage drain current	I <sub>DSS</sub>			-	-1	μA	
Gate - Source leakage current	I <sub>GSS</sub>	V <sub>DS</sub> = 0V, V <sub>GS</sub> = ±20V		-	±100	nA	
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -1mA$		-	-2.5	V	
Gate threshold voltage temperature coefficient	$\frac{\DeltaV_{\text{GS(th)}}}{\DeltaT_{j}}$	<del></del>		2.9	-	mV/°C	
Static drain - source	D *4	V <sub>GS</sub> = -10V, I <sub>D</sub> = -4.0A	-	55	70	0	
on - state resistance	R <sub>DS(on)</sub> *4	V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -4.0A	-	80	103	mΩ	
Gate resistance	$R_{G}$	f=1MHz, open drain	-	13	-	Ω	
Forward Transfer Admittance	Y <sub>fs</sub>  *4	$V_{DS} = -5V, I_{D} = -3A$	2.5	-	-	S	

<sup>\*1</sup> Pw  $\leq$  10 $\mu$ s, Duty cycle  $\leq$  1%

<sup>\*2</sup> L  $\simeq$  1mH, V<sub>DD</sub> = -15V, R<sub>G</sub> = 25 $\Omega$ , STARTING T $_{j}$  = 25 $^{\circ}$ C Fig.3-1,3-2

<sup>\*3</sup> Mounted on a Cu board (40×40×0.8mm)

<sup>\*4</sup> Pulsed

# ● Electrical characteristics (T<sub>a</sub> = 25°C) < Tr1 and Tr2>

Darameter	Symbol	Conditions		Unit		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offit
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	305	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = -15V	1	55	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	1	43	-	
Turn - on delay time	t <sub>d(on)</sub> *4	$t_{d(on)}^{*4}$ $V_{DD} \simeq -15V, V_{GS} = -10V$		7.4	-	
Rise time	me t <sub>r</sub> *4		1	9.1	-	no
Turn - off delay time	t <sub>d(off)</sub> *4	$R_L = 7.5\Omega$		26	-	ns
Fall time	t <sub>f</sub> *4	$R_G = 10\Omega$	-	13	-	

# ● Gate charge characteristics (T<sub>a</sub> = 25°C) < Tr1 and Tr2>

Darameter	Cumbal	Symbol Conditions -		Values			l limit
Parameter	Symbol			Min.	Тур.	Max.	Unit
Total mate above	O *4		V <sub>GS</sub> = -10V	-	6.7	-	
Total gate charge	$Q_g^{*4}$	V <sub>DD</sub> ≃ -15V		-	3.4	-	<b>~</b> C
Gate - Source charge	Q <sub>gs</sub> *4	I <sub>D</sub> = -4A	V <sub>GS</sub> = -4.5V	-	1.1	-	nC
Gate - Drain charge	Q <sub>gd</sub> *4			-	1.3	-	

# ● Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

# <Tr1 and Tr2>

Parameter	Symbol	Conditions	Values			Unit
raianetei	Symbol	Conditions	Min.	Тур.	Max.	Offic
Continuous forward current	I <sub>S</sub>	T = 25°C	-	-	-1.67	^
Pulse forward current	I <sub>SP</sub> *1	- T <sub>a</sub> = 25°C	-	-	-12	А
Forward voltage	V <sub>SD</sub> *4	V <sub>GS</sub> = 0V, I <sub>S</sub> = -1.67A	-	-	-1.2	V

Fig.1 Power Dissipation Derating Curve

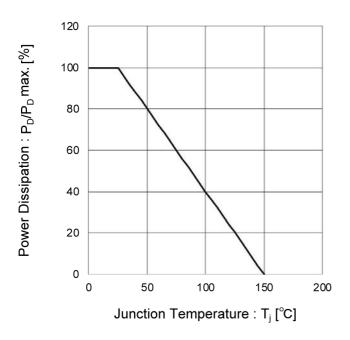
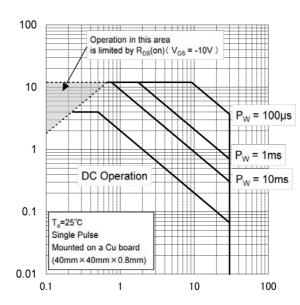


Fig.2 Maximum Safe Operating Area



Drain Current: -l<sub>D</sub> [A]

Drain - Source Voltage : -V<sub>DS</sub> [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

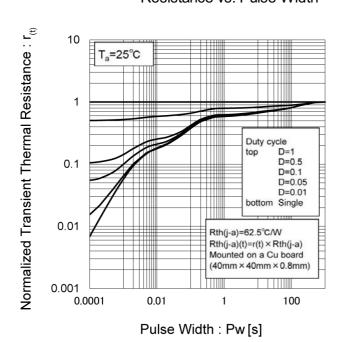
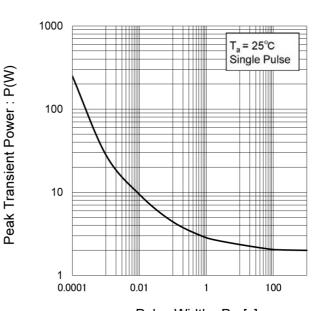


Fig.4 Single Pulse Maximum Power dissipation



Pulse Width : Pw [s]

Fig.5 Typical Output Characteristics(I)

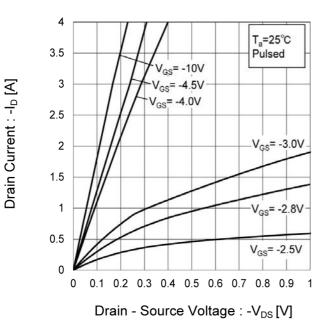
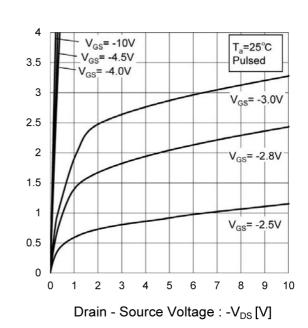


Fig.6 Typical Output Characteristics(II)



Drain Current : -I<sub>D</sub> [A]

Fig.7 Breakdown Voltage vs. Junction Temperature

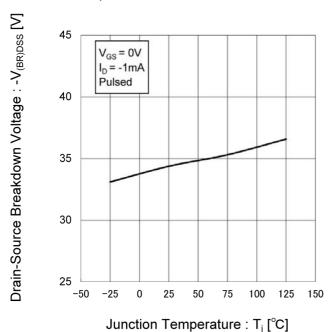


Fig.8 Typical Transfer Characteristics

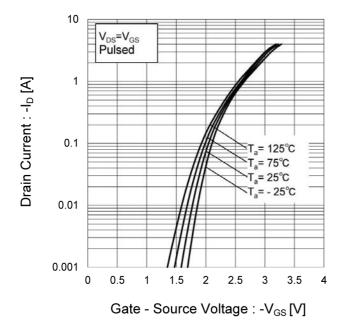
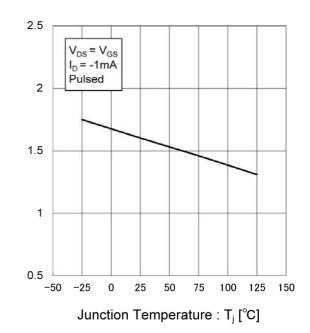


Fig.9 Gate Threshold Voltage vs. Junction Temperature



Gate Threshold Voltage : - $V_{GS(th)}$  [V]

Fig.10 Forward Transfer Admittance vs. Drain Current

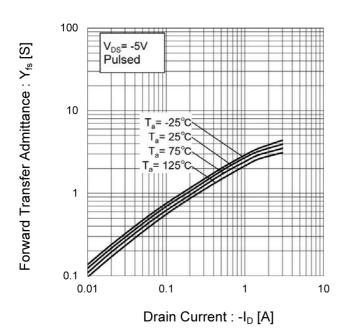


Fig.11 Drain Current Derating Curve

Drain Current Dissipation

Orange (%) 80

Junction Temperature : T<sub>j</sub> [°C]

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

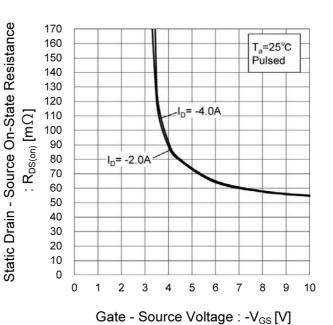
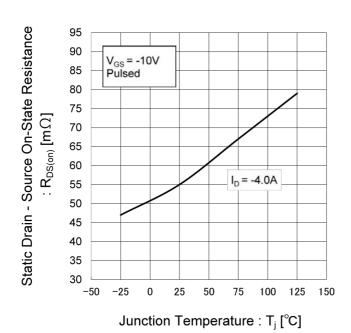


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature



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Fig.14 Static Drain - Source On - State Resistance vs. Drain Current(I)

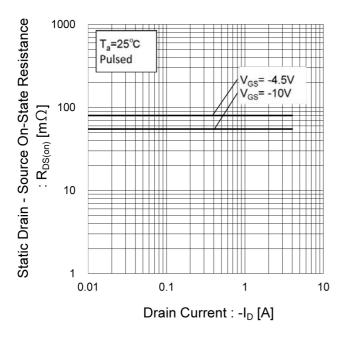


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(II)

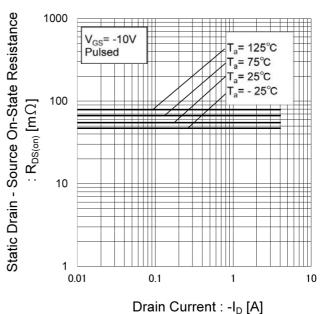


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III)

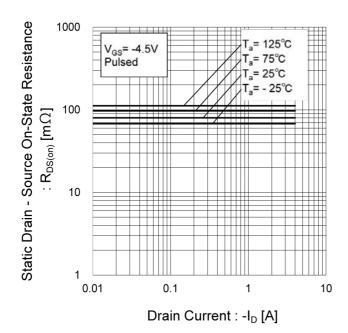


Fig.17 Typical Capacitance vs. Drain - Source Voltage

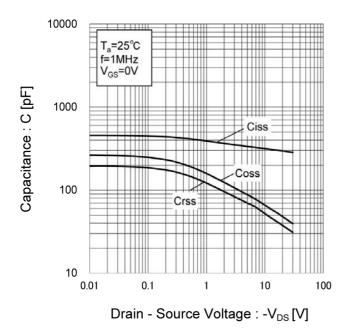


Fig.18 Switching Characteristics

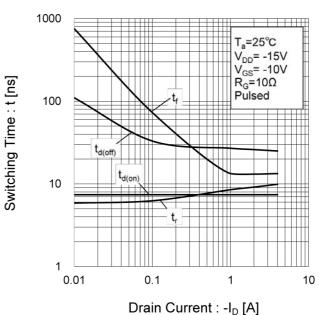


Fig.19 Dynamic Input Characteristics

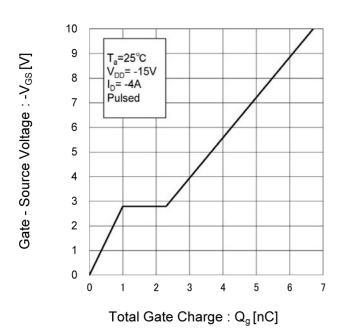
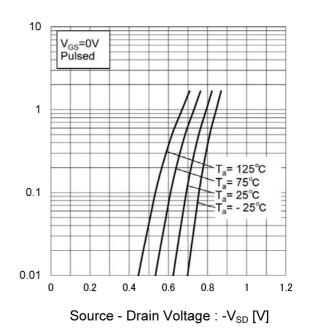


Fig.20 Source Current vs. Source Drain Voltage



Source Current : -I<sub>s</sub> [A]

# • Measurement circuits < It is the same for the Tr1 and Tr2>

Fig.1-1 Switching Time Measurement Circuit

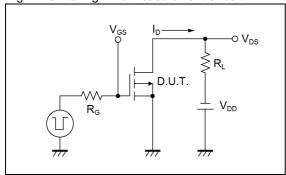


Fig.2-1 Gate Charge Measurement Circuit

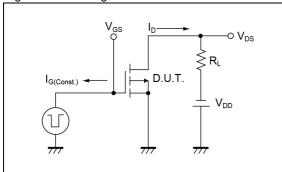


Fig.3-1 Avalanche Measurement Circuit

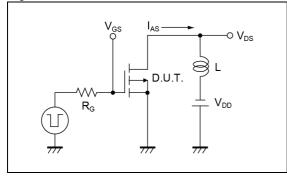


Fig.1-2 Switching Waveforms

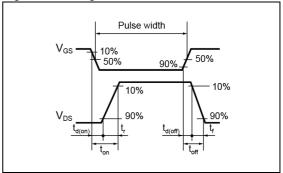


Fig.2-2 Gate Charge Waveform

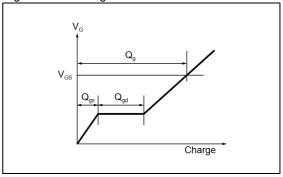
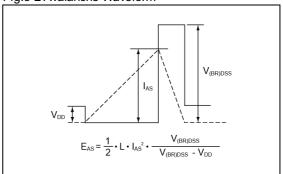


Fig.3-2 Avalanche Waveform

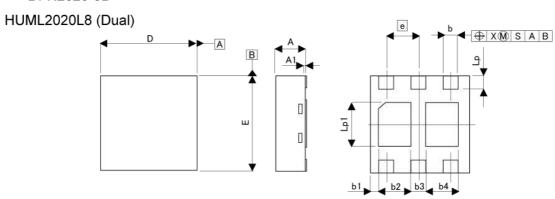


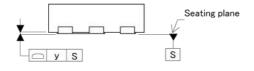
## Notice

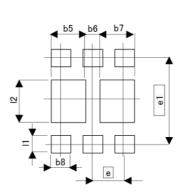
This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

# Dimensions

### DFN2020-8D







Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIME	TERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	0.55	0.65	0.022	0.026	
A1	0.00	0.05	0.000	0.002	
b	0.25	0.35	0.010	0.014	
b1	0.:	25	0.0	010	
b2	0.60	0.70	0.024	0.028	
b3	0.3		0.0	0.012	
b4	0.60	0.70	0.024	0.028	
D	1.90	2.10	0.075	0.083	
E	1.90	2.10	0.075	0.083	
е	0.	65	0.0	26	
Lp	0.225	0.325	0.009	0.013	
Lp1	0.80	1.00	0.031	0.039	
x	-	0.10	30 <del>4</del> 3	0.004	
٧	-	0.10	p. <del>e</del> .	0.004	

DIM -	MILIME	ETERS	INC	HES
DIIVI F	MIN	MAX	MIN	MAX
b5	-	0.70	5.51	0.028
b6	0.20	0.30	0.008	0.012
b7	-	0.70	0#0	0.028
b8	-	0.45	- 14	0.018
e1	1.7	725	0.0	068
11	-	0.425	9.50	0.017
12	- 2	1.00	(E)	0.039

Dimension in mm/inches



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JAPAN	USA	EU	CHINA
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CLASSIV	CLASSIII	CLASSⅢ	CLASSIII

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  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
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  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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For details, please refer to ROHM Mounting specification

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
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- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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